

IN THE CLAIMS

Please cancel claims 1 through 15, and add claims 16 through 46, as set forth below.

1 – 15. (canceled)

16. (new) A substrate material for an optical component for X-rays of wavelength λ_R , comprising:

a glass phase made of amorphous material having a positive coefficient of thermal expansion; and

a crystal phase including microcrystallites having a negative coefficient of thermal expansion and a mean size of less than about $4 \lambda_R$,

wherein said substrate material has a stoichiometric ratio of said crystal phase to said glass phase such that a coefficient of thermal expansion of said substrate material is less than about $5 \times 10^{-6} \text{ K}^{-1}$ in a temperature range of about 20°C to 100°C , and wherein said substrate material, following a surface treatment, has a high spatial frequency roughness (HSFR) of less than about $\lambda_R/30$ rms.

17. (new) The substrate material of claim 16, wherein said coefficient of thermal expansion of said substrate material is less than about $1 \times 10^{-6} \text{ K}^{-1}$ in said temperature range.

18. (new) The substrate material of claim 16, wherein said mean size is less than about $2 \lambda_R$.

19. (new) The substrate material of claim 16, wherein said mean size is less than about λ_R .

20. (new) The substrate material of claim 16, wherein said mean size is less than about $2\lambda_R/3$.

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21. (new) The substrate material of claim 16, wherein said mean size is less than about $\lambda_R/2$.

22. (new) The substrate material of claim 16, wherein said HSFR is less than about $\lambda_R/50$ rms.

23. (new) The substrate material of claim 16, wherein said HSFR is less than about $\lambda_R/100$ rms.

24. (new) The substrate material of claim 16, wherein said wavelength λ_R is in a range of about 10 nm to 30 nm.

25. (new) The substrate material of claim 16, wherein said surface treatment includes superpolishing a surface of said substrate material, and thereafter, beam processing said surface.

26. (new) The substrate material of claim 16, wherein said substrate material has a low spatial frequency roughness in a range of about $\lambda_R/50$ to $\lambda_R/100$ rms.

27. (new) The substrate material of claim 16, wherein said substrate material has a middle spatial frequency roughness (MSFR) in a range of about $\lambda_R/50$ to $\lambda_R/100$ rms.

28. (new) The substrate material of claim 27, wherein said MSFR is achieved by beam processing a surface of said substrate material.

29. (new) The substrate material of claim 16, wherein said optical component is a reticle mask.

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30. (new) The substrate material of claim 16, wherein said optical component is a normal-incidence mirror providing reflectivity of greater than about 70% to said X-rays at non-grazing incidence.

31. (new) The substrate material of claim 30, wherein said normal-incident mirror has an aspherical shape.

32. (new) The substrate material of claim 16, further comprising a layered pair of materials thereon selected from the group consisting of Mo/Si, Mo/Bi, and MoRu/Be.

33. (new) The substrate material of claim 32, comprising about 40 to 200 layers of said layered pairs of material.

34. (new) A substrate material for an optical component for X-rays of wavelength $10 \text{ nm} \leq \lambda_R \leq 30 \text{ nm}$ comprising:

a glass phase made of amorphous material having a positive coefficient of thermal expansion; and

a crystal phase including microcrystallites having a negative coefficient of thermal expansion and a mean size of less than about 38 nm,

wherein said substrate material has a stoichiometric ratio of said crystal phase to said glass phase such that a coefficient of thermal expansion of said substrate material is less than about $5 \times 10^{-6} \text{ K}^{-1}$ in a temperature range of about 20°C to 100°C, and wherein said substrate material, following a surface treatment, has a high spatial frequency roughness (HSFR) of less than about $\lambda_R/30$ rms.

35. (new) The substrate material of claim 34, wherein said mean size is less than about 20 nm.

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36. (new) The substrate material of claim 34, wherein said mean size is less than about 10 nm.

37. (new) An optical component for X-rays of wavelength λ_R , comprising:
a substrate material that includes:

a glass phase made of amorphous material having a positive coefficient of thermal expansion; and

a crystal phase including microcrystallites having a negative coefficient of thermal expansion and a mean size of less than about $4 \lambda_R$,

wherein said substrate material has a stoichiometric ratio of said crystal phase to said glass phase such that a coefficient of thermal expansion of said substrate material is less than about $5 \times 10^{-6} \text{ K}^{-1}$ in a temperature range of about 20°C to 100°C, and

wherein said substrate material, following a surface treatment, has a high spatial frequency roughness (HSFR) of less than about $\lambda_R/30$ rms.

38. (new) The optical component of claim 37, wherein said optical component is a mirror selected from the group consisting of a normal-incidence mirror and a grazing-incidence mirror.

39. (new) The optical component of claim 37, wherein said optical component is a reticle mask.

40. (new) A method for producing a substrate material for an optical component for X-rays of wavelength λ_R , comprising:

superpolishing a surface of said substrate material until achieving a high spatial frequency roughness (HSFR) of less than about $\lambda_R/30$ rms; and

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beam processing said surface until achieving a low spatial frequency roughness in a range of about $\lambda_R/50$ to $\lambda_R/100$ rms and a middle spatial frequency roughness (MSFR) in a range of about $\lambda_R/50$ to $\lambda_R/100$ rms, wherein said HSFR is maintained at less than about $\lambda_R/30$ rms after said beam processing.

41. (new) The method of claim 40, wherein said superpolishing is performed until said HSFR is less than about $\lambda_R/50$ rms.

42. (new) The method of claim 40, wherein said superpolishing is performed until said HSFR is less than about $\lambda_R/100$ rms.

43. (new) An EUV projection system, comprising:
an illumination system for illuminating a mask; and
a projection lens system for projecting an image of said mask,
wherein at least one of said illumination system or said projection lens system includes an optical component for X-rays of wavelength λ_R having a substrate material that includes (a) a glass phase made of amorphous material having a positive coefficient of thermal expansion, and (b) a crystal phase including microcrystallites having a negative coefficient of thermal expansion and a mean size of less than about $4 \lambda_R$, wherein said substrate material has a stoichiometric ratio of said crystal phase to said glass phase such that a coefficient of thermal expansion of said substrate material is less than about $5 \times 10^{-6} \text{ K}^{-1}$ in a temperature range of about 20°C to 100°C , and wherein said substrate material, following a surface treatment, has a high spatial frequency roughness (HSFR) of less than about $\lambda_R/30$ rms.

44. (new) A system comprising a substrate material that includes:
a glass phase made of amorphous material having a positive coefficient of thermal expansion; and

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a crystal phase including microcrystallites having a negative coefficient of thermal expansion and a mean size of less than about $4 \lambda_R$,
wherein said substrate material has a stoichiometric ratio of said crystal phase to said glass phase such that a coefficient of thermal expansion of said substrate material is less than about $5 \times 10^{-6} \text{ K}^{-1}$ in a temperature range of about 20°C to 100°C,
wherein said substrate material, following a surface treatment, has a high spatial frequency roughness (HSFR) of less than about $\lambda_R/30$ rms, and
wherein said system is selected from the group consisting of an X-ray microscopy system, an X-ray astronomy system, and X-ray spectroscopy system.

45. (new) A substrate material for an optical component for X-rays of wavelength $10 \text{ nm} \leq \lambda_R \leq 30 \text{ nm}$, comprising:

an amorphous material having a positive coefficient of thermal expansion; and
crystallites having a negative coefficient of thermal expansion and being a mean size of less than about 38 nm,
wherein the substrate material has a coefficient of thermal expansion of less than about $5 \times 10^{-6} \text{ K}^{-1}$ in a temperature range of about 20°C to 100°C, and
wherein the substrate material has a high spatial frequency roughness (HSFR) of less than about $\lambda_R/30$ rms.

46. (new) The substrate material of claim 45, wherein the substrate material has a middle spatial frequency roughness (MSFR) in a range of about $\lambda_R/50$ to $\lambda_R/100$ rms, and a low spatial frequency roughness in a range of about $\lambda_R/50$ to $\lambda_R/100$ rms.